

Review

Chemical sensors based on nanostructured materials

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Abstract

This article provides a comprehensive review of current research activities that concentrate on chemical sensors based on nanotubes, nanorods, nanobelts, and nanowires. We devote the most attention on the experimental principle, design of sensing devices, sensing mechanism, and some important conclusions. We elaborate on development of chemical sensors based on nanostructured materials in the following four sections: (1) nanotube sensors; (2) nanorod sensors; (3) nanobelt sensors; (4) nanowire sensors. We conclude this review with personal perspectives on the directions towards which future research on nanostructured sensors might be directed.

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Keywords: Chemical sensors; Nanotubes; Nanorods; Nanobelts; Nanowires

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1. Introduction

The most important aspect of investigation of a variety of sensors is 3 ‘S’, i.e. sensitivity, selectivity, and stability. Up to now,

great efforts have been made to better resolve these problems, such as research on novel sensing materials research [1–3], data analytical method (FFT and wavelet transform, pattern recognition) [4,5], measurement techniques (static and dynamic) [6–9], control of sensors structures (arrays) [10,11], sensor fabrication techniques [12–17], surface modification [18,19], etc. With the development of nano-science and technology, a large number of literatures on one-dimensional nanostructured materials,

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including tubes, rods, belts, and wires in this area, have been published every year. These materials have their unique structure; it is evident that the structure of nanowires and nanorods is similar to each other which are dominated by a wire-like structure whose diameter varies over a broad range from several tens of nanometers to a micrometer. The typical length of the nanowires ranges from several tens to several hundred micrometers, whereas the length of nanorods is only several micrometers. TEM observation indicates that nanotubes possess the wire-like nanostructures with hollow cores. Considering the contrast over the length of the nanostructure and the results of chemical imaging, the belt-like nanostructure is found to have a rectangular cross-section. Each nanobelt has a uniform width along its entire length, and the typical widths of the nanobelts are in the range of several tens to several hundred nanometers. Due to their interesting structures, it provides many opportunities to study their interesting sensing behavior by making new types of nanosensing structures. In this article, we give a comprehensive review of current research activities that concentrate on chemical sensors based on nanotubes, nanorods, nanobelts, and nanowires. Due to the large amount of literatures, the following narrative highlights researches published in the past 5 years in this busy field. Though sensor applications of carbon nanotubes have been researched by a number of authors, we intend to exclude them from the scope of this article. This review is divided into four sections. In each section, we focus on the experimental principle, design of sensing devices, sensing mechanism, and some important conclusions. The article concludes with a brief comments and outlook concerning the sensor application of one-dimensional nanomaterials.

2. Nanotube sensors

In general, nanotube-based sensors include metal oxide tubes such as Co_3O_4 , Fe_2O_3 , SnO_2 , and TiO_2 and metal tubes such as Pt nanosensor.

Li et al. [20] presented that Co_3O_4 nanotubes exhibited superior gas sensing capabilities towards H_2 . The sensor was fabricated by casting the mixture of nanotubes and ethanol on ceramic tubes with the connection through gold electrodes that were connected by four platinum wires. They suggested that the change of resistance was mainly caused by the adsorption and desorption of gas molecules on the surface of the sensing structure; the hollow inside the tubes and the porous surface of the Co_3O_4 nanotubes could provide more active sites in the three dimensional structure, and enabled the detecting gases to access more surfaces. They also found that $\alpha\text{-Fe}_2\text{O}_3$ exhibited high sensitivity to H_2 and $\text{C}_2\text{H}_5\text{OH}$ at room temperature [21].

Recently, Liu and Liu [22] reported a single square shaped SnO_2 nanotube gas sensor to ethanol which was bridged to two interdigitated Pt electrodes. They suggested that the advantages included the dramatically accelerated transport of gas/liquid in and out of the box beams, significantly increased active surface areas and increased flexibility in surface modification for chemically or biologically selective catalysis, drastically enhanced transport of ionic and electronic defects in the solid state (perpendicular to the wall thickness) due to shorter diffu-

sion lengths, radically increased population of defects at surfaces/interfaces for fast electrode kinetics, and quantum interactions at the nanoscale. Huang et al. [23] studied responses of a SnO_2 nanotube sheet sensor to 100 ppm H_2 , 100 ppm CO, and 20 ppm ethylene oxide. The sheet (0.2 mm in thick) was of about $2\text{ mm} \times 4\text{ mm}$ in size and was fixed with gold paste onto an alumina substrate attached with gold electrodes having a gap of 1 mm.

Also of interest is the research of Grimes and co-workers [24–27] who described a room temperature hydrogen sensor comprised of a TiO_2 nanotube array capable to recover substantially from sensor poisoning through ultraviolet (UV) photocatalytic oxidation of the contaminating agent. A 10 nm coating of Pd was evaporated onto the surface of the titania nanotube array film to enhance the hydrogen sensitivity of the sensor, which showed over a 170,000% change in electrical resistance upon exposure to 1000 ppm hydrogen at 24°C . They suggested that adsorbed oxygen played a major role in manipulating the conductivity. On UV illumination, the chemisorbed oxygen must be desorbed, increasing the conductivity. Hence, the conductivity increase upon UV exposure has one part from the photogenerated current and another part from the electrons donated by the desorbed oxygen. On removing the UV illumination, oxygen will be re-adsorbed and hence the electrons will be extracted from the sensor. However, the process of oxygen re-adsorption is slow, on the order of several minutes, and hence it takes a relatively long time to regain the original sensor resistance after the UV illumination is removed.

Xia and co-workers [28] systematically investigated the glucose electrochemical-sensing behavior directly using highly ordered platinum-nanotube array electrodes (NTAEs) supported on a gold substrate. The authors suggested that NTAEs were easily regenerated by electrochemical cleaning, and were mechanically and chemically stable. Meanwhile, NTAEs retain high sensitivity in the presence of chloride ions, which is essential for use as enzyme-free electrochemical sensors. Such a glucose sensor allows the determination of glucose in a linear range of 2–14 mM, with a sensitivity of $0.1\ \mu\text{A cm}^{-2}\ \text{mM}^{-1}$ and a detection limit of 1.0 μM glucose, with negligible interference from physiological levels of 0.1 mM *p*-acetamedophenol, 0.1 mM ascorbic acid, and 0.02 mM uric acid.

3. Nanorod sensors

Generally a large number of repetitive steps of nanorod-based sensors are involved in metal oxide nanorods such as ZnO, MoO_3 , and tungsten oxide nanosensors, polymer nanorods such as poly(3,4-ethylene-dioxythiophene) nanosensor, and metal nanorods such as Au nanosensor. Among these researches, most attention has been focused on ZnO nanorods sensors.

Wang and co-workers [29,30] fabricated thick film sensors based on ZnO nanorods. The paste prepared from a mixture of ZnO nanorods with a polyvinyl alcohol solution was coated onto an Al_2O_3 tube on which two gold leads had been installed at each end. A heater of Ni–Cr wire was inserted into the Al_2O_3 tube to supply the operating temperature which was controlled in the range of $100\text{--}500^\circ\text{C}$. The nanorod sensors could detect 1 ppm

C₂H₅OH (350 °C) and 0.05 ppm H₂S (25 °C). They suggested that the gas response was mainly dependent upon two factors. The first is the amount of active sites for oxygen and the reducing gases on the surface of the sensor materials. The more active sites the surface of nanosensor contain, the higher sensitivity the sensor exhibits. The second is the reactivity of the reducing gases. The bond energy of H–SH is 381 kJ/mol [31], so that it is easy to open the bond H–SH at lower temperature. On the other hand, the bond energies H–CH₂, H–OC₂H₅ and H–CH in C₂H₅OH are 473, 436 and 452 kJ/mol [31], respectively, so that it is difficult to open the bonds in C₂H₅OH at lower temperature. Kang et al. [32] reported that multiple ZnO nanorods are sensitive to H₂ at 112 °C or O₃ at room temperature. They also found that ZnO nanorods showed dramatic changes in conductance upon exposure to polar liquids [33]. The results indicate the possibility of functionalizing the surface for application as biosensors, especially given the excellent biocompatibility of the ZnO surfaces, which should minimize degradation of adsorbed cells. Wang and co-workers presented the sensitivity to 10 ppm H₂ and 1000 ppm C₂H₅OH of Pd/multiple [34] and multipod shaped [35] ZnO nanorods sensors. The dominant mechanism for this sensing process is more likely to be the chemisorption of hydrogen on the Pd surface. Multipod ZnO nanorods which have more than four even tens of needle-like nanorods [36] at a common junction resulted in a very large surface area, and therefore their sensing properties related to the surface reactions could be greatly enhanced. Xu et al. [37,38] found the treatment process of ZnO nanorods had obvious effect on its gas sensing properties to HCHO, LPG, and H₂S.

Zhang et al. [39] reported ZnO nanorods for a reagentless uric acid biosensor. The uricase/ZnO biosensor was constructed by casting uricase on the ZnO membrane. The electrocatalytic response showed a linear dependence on the uric acid concentration ranging from 5.0×10^{-6} to 1.0×10^{-3} M with a detection limit of 2 μM. In their work, ZnO nanorods played the role of an efficient electron-conducting tunnel and had a very high specific surface area. Consequently, the uricase attached to the ZnO nanorods surface had more spatial freedom in its orientation, which facilitated the direct electron transfer between the active sites of the immobilized uricase and the electrode surface.

Comini et al. [40] presented the high sensitivity of a MoO₃ nanorods film sensor to 30 ppm carbon monoxide and 100 ppm ethanol. Kim et al. [41] studied a gas sensor based on a nonstoichiometric tungsten oxide nanorod film. The sensor was fabricated on Si wafers as the substrates by using microelectromechanical system (MEMS) and silicon technology. The authors measured the sensor responses to 2% N₂ (or air), 1000 ppm ethanol, 10 ppm NH₃, and 3 ppm NO₂ in both dry air and nitrogen atmosphere at room temperature. Their response magnitudes ascend in the order of air, C₂H₅OH, NH₃, and NO₂ exposures.

Sudeep et al. [42] reported a novel strategy for the selective detection of micromolar concentrations of cysteine (3 μM) and glutathione (12 μM) by exploiting the interplasmon coupling in Au nanorods. Firstly, the thiol group of cysteine/glutathione molecules is selectively functionalized onto the edges of Au nanorods, leaving the zwitterionic groups for further interaction. Secondly, the appended zwitterionic groups at the ends of

Au nanorods assist the coupling through a two-point electrostatic interaction in a cooperative fashion. Sönnichsen and Alivisatos [43] reported an ideal probe for orientation sensing in material science and molecular biology by monitoring the polarized light scattering from individual gold nanorods in a darkfield microscope.

Jang et al. [44] presented a poly(3,4-ethylene-dioxythiophene) (PEDOT) nanorods nanosensor and used it for the detection of HCl and NH₃ vapor. The PEDOT nanorode sensors gave a measurable response to NH₃ and HCl vapor concentration as low as 10 and 5 ppm, respectively. The recovery time of PEDOT nanorod sensors for NH₃ and HCl was about 70 and 80 s, respectively.

4. Nanobelt sensors

As for nanobelt-based sensors, the main attentions have been focused on metal oxides such as ZnO, SnO₂ and V₂O₅ nanosensors, especially on ZnO nanobelts sensors. The ability of SnO₂ field-effect transistors to act as oxygen sensors is demonstrated by Wang and co-workers [45]. They have also assembled tin dioxide nanobelts with low-power microheaters for detecting dimethyl methylphosphonate, a nerve agent stimulant [46]. A focused ion beam method was used to deposit a thin Pt coating on the contact location between the nanobelt and each Pt electrode so as to improve the electrical contact. Again, they reported gas sensors to detect environmental polluting species based on single SnO₂ nanobelts, like CO and NO₂ sensors, ethanol sensors for breath analyzers, and food sensors [47]. The detection limit reaches the level of a few ppb.

Yang and co-workers [48] reported photochemical NO₂ sensors based on individual single-crystalline SnO₂ nanoribbons that worked at room temperature. The resolution limit of the sensor was 5–10 ppm. They further [49] found that SnO₂ nanoribbons with exposed (10 $\bar{1}$) and (010) surfaces were highly effective NO₂ sensors at room temperature. The sensing mechanism was examined through the first principles of density functional theory (DFT) calculations. Kolmakov et al. [50] investigated the sensing ability of individual SnO₂ nanobelts before and after functionalization with Pd catalyst particles. The Pd-functionalized nanostructures exhibited a dramatic improvement in sensitivity toward oxygen and hydrogen due to the enhanced catalytic dissociation of the molecular adsorbate on the Pd nanoparticle surfaces and the subsequent diffusion of the resultant atomic species to the oxide surface. Faglia et al. [51] presented that the visible photoluminescence (PL) of SnO₂ nanobelts could be quenched by nitrogen dioxide at a ppm level in a fast (time scale order of seconds) and reversible way. NO₂⁻ involved surface states responsible for PL quenching are probably the ones with lower binding energies and negligible net charge transfer that could easily and quickly be adsorbed and desorbed from the oxide surface, such as the species [NO₂]₂,Sn_nO identified by Maiti et al. [49]. Gao and Wang [52] found that the SnO₂ nanobelt/CdS nanoparticle core/shell heterostructured sensor had high sensitivity to 100 ppm ethanol vapors in air at 400 °C. The authors suggested that the CdS nanoparticles would have served as additional electron sources that greatly improved

the electron conduction in the SnO₂ nanobelts. Kong and Li [53] presented a highly sensitive and selective CuO–SnO₂ sensor to H₂S based on SnO₂ nanoribbons. Comini et al. [54] proposed a SnO₂ nanobelts film for gas sensing and proved its capability to reveal of gases like 30 ppm CO (350 °C), 200 ppb NO₂ (300 °C), and 10 ppm ethanol (350 °C).

A novel highly selective and stable ethanol sensor based on single-crystalline divanadium pentoxide nanobelts was reported by Li and co-workers [55]. The V₂O₅ nanobelts showed greater sensitivity to ethanol of either low (<10 ppm) or high (1000 ppm) concentrations. The response and recovery times were 30–50 s.

5. Nanowire sensors

5.1. Metal nanowire sensors

Penner and co-workers [56] reported hydrogen sensors and switches based on electrodeposited palladium mesowire arrays (PMAs). These sensors consisted of up to 100 Pd mesoscopic wires (henceforth, “mesowires”) arrayed in parallel (Fig. 1, left, A and B), which contacted with silver epoxy. A rise-time (baseline to 90% signal saturation) of less than 80 ms was observed for the response of the mesowire-based sensors to 5% H₂. They suggested that the hydrogen sensing mechanism of the wire-based sensor was based on the resistivity changes caused not by the surface adsorption but by the structure changes of the wire itself, as shown in Fig. 1 (right). After the first exposure to H₂, exposure to air opened the nanoscopic gaps in some or all mesowires in the sensor. These gaps opened when the hydrogen-swollen Pd grains in each mesowire returned to their equilibrium dimensions in the absence of hydrogen. Subsequently, it was the closing of these gaps or “break junctions” in the presence of H₂ that accounted for the decreased resistance of the sensor. Many or all of the mesowires in the array exhibited this kind of switch-

ing behavior. Penner and co-workers [57,58] also demonstrated that the ensembles of silver mesowires with diameters ranging from 150 to 950 nm and lengths of 100 μm or more showed a resistance increase, fast (<5 s), and reversible, upon exposure to ammonia (NH₃).

Pd nanowire-based hydrogen sensors and polypyrrole nanowire-based pH sensors were demonstrated by Yun et al. [59]. Using a single electrodeposited Pd wire with a 1 μm diameter and a 7 μm length, they demonstrated the sensing of hydrogen gas of different concentrations (1–3% in N₂ gas). Similarly, Atashbar and Singamaneni [60] investigated a room temperature hydrogen gas sensor based on palladium nanowires.

Yang et al. [61] demonstrated the capability of silver nanowire substrates for the detection of 2,4-dinitrotoluene (2,4-DNT), the most common nitroaromatic compound for detecting buried landmines, and other explosives by utilizing vibrational signatures. The sensitivity of about 0.7 pg was achieved.

Tao and co-workers [62] studied the sensing behaviors of Cu nanowire arrays in solutions of three molecules; 2,2'-bipyridine (22BPY), adenine, and mercaptopropionic acid (MPA). They demonstrated that the mechanism depended on the molecule–nanowire interactions and the conductance changes should be specific for different adsorptions. The specificity can be improved if the nanowires are pre-adsorbed with functionalized molecules because a specific interaction of a sample molecule with the functionalized molecules provides identity information about the sample molecule.

5.2. Silicon nanowire nanosensors

Lieber’s group has done a series of excellent works for silicon nanowire-based sensors. They presented highly sensitive and real-time sensors based on electrically boron-doped silicon nanowires (SiNWs) for detecting a biological and chemical

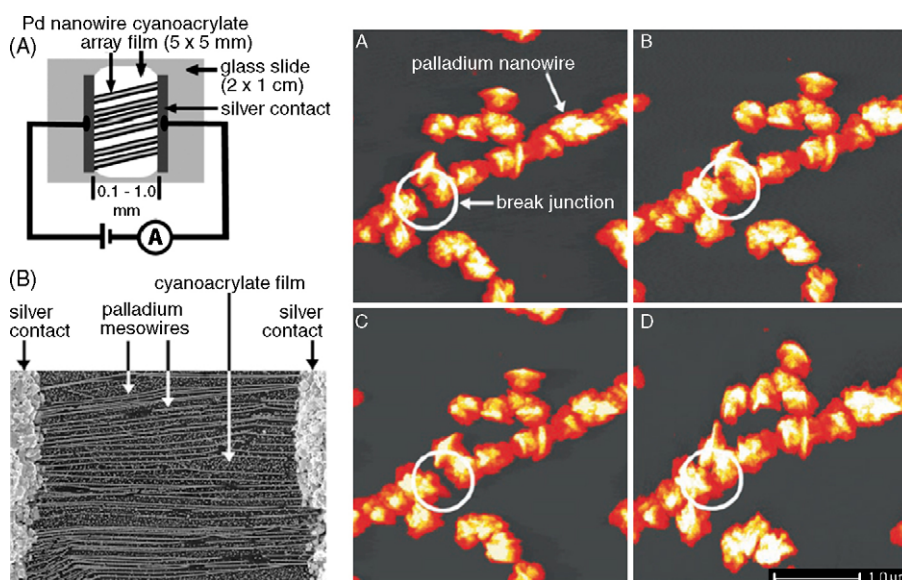


Fig. 1. (Left) (A) Schematic diagram of a PMA-based hydrogen sensor or switch. (B) SEM image of the active area of a PMA-based hydrogen sensor. (Right) Atomic force microscope images of a Pd mesowire on a graphite surface. Images (A) and (C) were acquired in air, and images (B) and (D) were acquired in a stream of hydrogen gas. A hydrogen-actuated break junction is highlighted.

species, amine, and the oxide-functionalized SiNWs exhibited pH-dependent conductance that was linear over a wide dynamic range [63].

They evaluated the response of 3-aminopropyltriethoxysilane-modified SiNW to changes in solution pH by fabricating a cell consisting of a microfluidic channel formed between a poly(dimethylsiloxane) mold and the SiNW/substrate [64]. Continuous flow or static experiments demonstrated that the SiNW conductance increases stepwise with discrete changes in pH from 2 to 9 and that the conductance was constant for a given pH; the changes in conductance were also reversible for increasing and/or decreasing the pH. These results could be understood by considering the change in surface charge during protonation and deprotonation after the surface functionality of the modified SiNWs. To explore biomolecular sensors, they functionalized SiNWs with biotin and studied the well-characterized ligand–receptor binding of biotin–streptavidin. Measurements showed that the conductance of the biotin-modified SiNWs increased rapidly to a constant value upon addition of a 250 nM streptavidin solution and that this conductance value was maintained after the addition of a pure buffer solution. They confirmed that the observed conductance changes were due to the specific binding of streptavidin to the biotin ligand.

Hahn and Lieber [65] also demonstrated that p-type SiNWs functionalized with peptide nucleic acid (PNA) receptors functioned as ultrasensitive and selective real-time DNA sensors at concentrations down to tens of femtomolar range. Direct, real-time electrical detection of single virus particles with high selectivity by using nanowire field-effect transistors was also

reported by Lieber and co-workers [66]. Measurements made with nanowire arrays modified with antibodies for influenza A showed discrete conductance changes characteristic of binding and unbinding in the presence of influenza A but not paramyxovirus or adenovirus. The authors suggested that the conductance of that device should change from the baseline value when a virus particle was bound to the antibody receptor on a nanowire device, and the conductance should return to the baseline value when the virus was unbound. Fig. 2 shows the parallel collection of conductance, fluorescence, and right-field data from a single nanowire device with fluorescently labeled viruses.

They continued to study a highly sensitive detection scheme for identifying small molecule inhibitors that did not require labeling of the protein, ATP, or small molecule and could be carried out in real-time by using SiNWs field-effect transistor (FET) devices [67]. They linked the Abl tyrosine kinase to the surface of SiNWs FET within microfluidic channels to create active electrical devices and investigated the binding of ATP and competitive inhibition of ATP binding with organic molecules, as shown schematically in Fig. 3 (left bottom). Plots of the normalized conductance versus time recorded from the Abl-modified SiNW devices (Fig. 3, right) exhibit reversible decreases in conductance due to competitive inhibition of ATP binding by small molecules.

Many interesting works on silicon nanowire-based nanosensors have also been reported by other group. Lee and co-workers [68] studied the chemical sensitivity of SiNWs bundles upon exposure to ammonia gas and water vapor. The sensors were made by pressing bundles of HF- and non-etched Si nanowires of

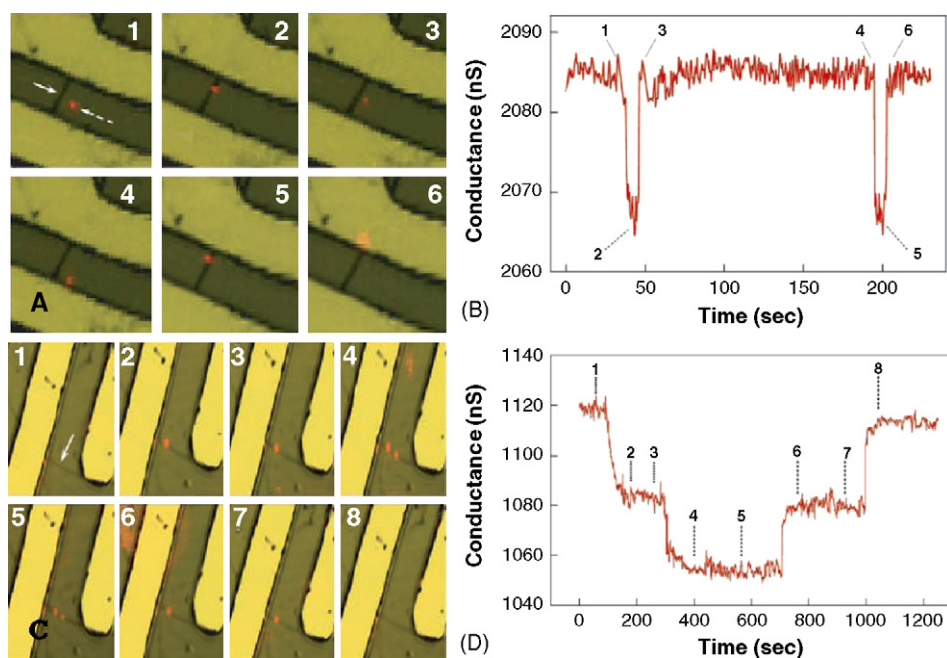


Fig. 2. Selective detection of single viruses. (A) Optical and (B) conductance data recorded simultaneously versus time for a single silicon nanowire device after introduction of influenza A solution. Combined bright-field and fluorescence images correspond to time points 1–6 indicated in the conductance data; virus appears as a red dot in the images. The solid white arrow in image 1 (A) highlights the position of the nanowire device, and the dashed arrow indicates the position of a single virus. Images are $8\ \mu\text{m} \times 8\ \mu\text{m}$. All measurements were performed with solutions containing 100 viral particles per microliter. (C) Optical and (D) simultaneous conductance vs. time data recorded from a single nanowire device with a high density of anti-influenza type A antibody. Influenza A solution was added before point 1, and the solution was switched to pure buffer between points 4 and 5 on the plot. The bright-field and fluorescence images corresponding to time points 1–8 are indicated in the conductance data; the viruses appear as red dots in the images. Each image is $6.5\ \mu\text{m} \times 6.5\ \mu\text{m}$.

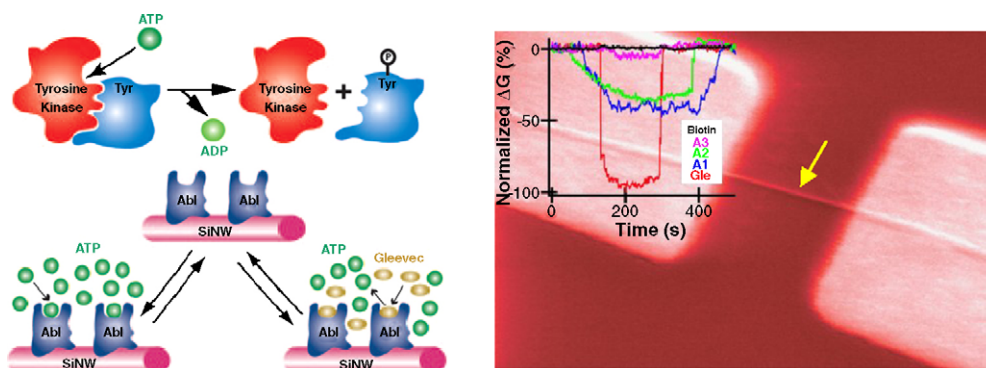


Fig. 3. Detection of small molecule–protein interactions for tyrosine kinases. (Left, top) Scheme illustrating basic activity of a tyrosine kinase: ATP binds to the tyrosine kinase active site, and then the γ -phosphate group is transferred to the tyrosine (Tyr) residue of the substrate protein. (Bottom) Detection of ATP binding and small molecule inhibition of binding by using a SiNW sensor device. The tyrosine kinase Abl is covalently linked to the surface of a SiNW, and then the conductance of the nanowire device is monitored to detect ATP binding and the competitive inhibition of ATP binding by Gleevec. (Right) Scanning electron micrograph of a typical SiNW FET device. The nanowire is highlighted by a yellow arrow and is contacted on either end of Ti–Au metal electrodes. (Inset) Normalized conductance vs. time data recorded from Abl-modified SiNW devices by using solutions containing 100 nM ATP and 50 nM small molecules for Gleevec (red), A1 (blue), A2 (green), A3 (pink), and biotin (black). (For interpretation of the references to color in this figure legend, the reader is referred to the web version of the article.)

about 0.4 mg onto the surface of insulating glasses. The sensing mechanism could be understood according to two possible ways, i.e. the contact resistance across two nanowires and the surface resistance along the individual nanowire. Bashir and co-workers [69] described silicon nanowire oxygen sensor that was realized using top–down microelectronics processing techniques. Unlike the idea of Lieber’s group, Hsu et al. [70] presented a SiNW-based pH sensor in an extended-gate field-effect transistor. They suggested that SiNWs could support a three-dimensional contact mode, resulting in a larger total surface area, and the SiNWs were cylindrical, which caused the non-bridging Si–O bonds of the surface to be of the suspended and standing types.

Li et al. [71,72] reported sequence-specific label-free DNA sensors based on SiNWs with peptide nucleotide acid (PNA) or single-stranded (ss) probe DNA molecules covalently immobilized on the nanowire surfaces. Label-free complementary (target) ss-DNA in sample solutions were recognized when the target DNA was hybridized with the probe DNA attached on the SiNW surfaces, producing a change of the conductance of the SiNWs. For a 12-mer oligonucleotide probe, 25 pM of the target DNA in solution was detected easily (signal/noise ratio > 6), whereas 12-mer with one base mismatch did not produce a signal above the background noise. Sheu et al. [73] demonstrated

molecular detection based on SiNWs whose surface was pre-treated by *N*-(2-aminoethyl)-3-aminopropyl-trimethoxysilane and then selectively deposited with gold nanoparticles. The gold nanoparticles deposited on the oxide surface of the SiNWs and then functionalized with amino groups served as linkers to detect molecules. The target molecules, such as Δ^5 -3-ketosteroid isomerase (KSI-126C) molecules, bound with gold nanoparticles on the surface of the SiNWs and resulted in a voltage shift.

Tong and co-workers [74] proposed to use single-mode subwavelength-diameter silica nanowires for optical sensing based on evanescent-wave guiding properties of the nanowire waveguides. The phase shift of the guided mode caused by index change was obtained by solving Maxwell’s equation, and was used as a criterion for sensitivity estimation. A nanowire sensor employing a wire assembled Mach–Zehnder structure was modeled. This silicon nanowire-based optical sensing may suggest a new approach to miniaturized optical sensors with high sensitivity. However, there are still some problems to be considered in the future such as instability of the nanowire-assembled couplers and oversensitivity of the whole system. The schematic diagram of the functionalized nanowire waveguides as sensing elements for detecting specimens in aqueous solutions is shown in Fig. 4.

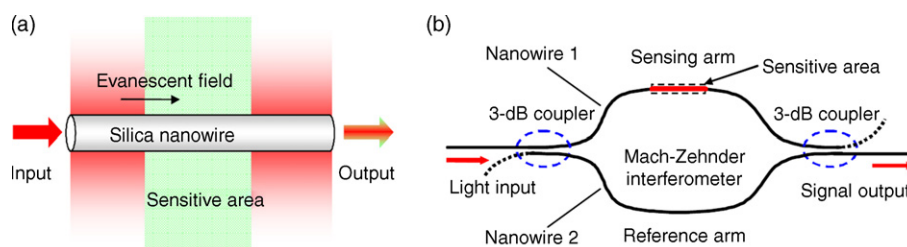


Fig. 4. (a) A silica nanowire sensing element exposed to or immersed in the solution to be detected (highlighted in light green), and the wire guides light as a single-mode waveguide. (b) A proposed sensor with a Mach–Zehnder interferometer. A Mach–Zehnder interferometer can be assembled with two uniform silica nanowires; nanowire 1 is used as a sensing arm with a certain length of sensitive area exposed to the measurand, and nanowire 2 is used as a reference arm that is kept under constant condition and is isolated from the measurand. (For interpretation of the references to color in this figure legend, the reader is referred to the web version of the article.)

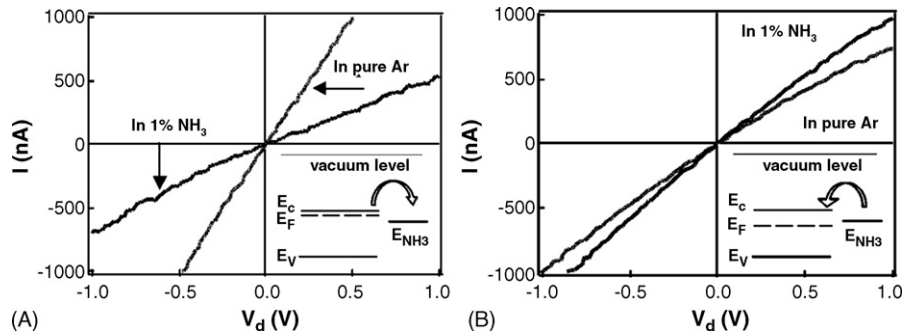


Fig. 5. (A) $I - V_d$ curves of sample 1 before and after exposure to 1% NH_3 . (Inset) Energy band diagrams of heavily doped In_2O_3 and NH_3 molecules. (B) $I - V_d$ curves of sample 2 before and after exposure to 1% NH_3 . (Inset) Energy band diagrams of lightly doped In_2O_3 and NH_3 molecules.

5.3. Metal oxide nanowire sensors

5.3.1. In_2O_3 nanowire sensors

Zhang and co-workers have done a series of wonderful works for In_2O_3 nanowire-based sensors. They demonstrated a single In_2O_3 nanowire to work as chemical sensors for NO_2 and NH_3 at room temperature [75]. The devices showed responses (defined as the resistance after exposure divided by the resistance before exposure) as high as 10^6 for diluted NO_2 and 10^5 for diluted NH_3 . The response times (defined as the time duration for resistance change by one order of magnitude) were determined to be 5 s for 100 ppm NO_2 and 10 s for 1% NH_3 , and the lowest detectable concentrations were 0.5 ppm for NO_2 and 0.02% for NH_3 . Continuously, they observed changes of conductance in opposite directions with different nanowire sensors [76,77]. They explained this case using a doping-dependent sensing mechanism; they suggested that the NH_3 -sensing behavior of In_2O_3 nanowires was related to their oxygen vacancy doping concentrations. Figs. 5A and B shows the $I - V_d$ curves before and after exposure to 1% NH_3 and the corresponding energy band diagrams for samples 1 and 2, respectively, where E_c , E_v and E_f correspond to the conduction band, the valence band and the Fermi level of the In_2O_3 nanowires. Once NH_3 molecules adsorb onto the In_2O_3 nanowire surface, electron transfer proceeds from the material with a higher chemical potential to the material with a lower chemical potential until the system reaches equilibrium. The hypothesis is that for sample 1, the heavily doped device, the nanowire Fermi level E_f is fairly close to the conduction band and located above E_{NH_3} (shown in the inset in Fig. 5A). Therefore, electrons should migrate from the nanowire to the adsorbed NH_3 species and result in a reduction

in the nanowire carrier concentration. This effectively leads to the observed suppressed conductance for sample 1. In contrast, a relatively low doping concentration has been found for sample 2, suggesting that E_f is well below the conduction band, presumably even below E_{NH_3} (the inset in Fig. 5B). As a result, electrons transfer from the adsorbed NH_3 molecules into the In_2O_3 nanowire and hence the enhanced conduction is observed after the exposure. This hypothesis is backed by calculation of the difference between E_c and E_f values for samples 1 and 2, which is estimated to be

$$(E_c - E_f)_{\text{sample1}} - (E_c - E_f)_{\text{sample2}} \\ = kT \ln(n_2/n_1) = 81.1 \text{ meV}$$

where n_1 and n_2 are the electron concentration for samples 1 and 2, respectively. This value is significant even at room temperature and may very well cause the electron transfer in opposite directions for nanowires with different doping concentrations.

Zhou and co-workers [78] also continuously demonstrated detection of NO_2 down to ppb levels using transistors based on both single and multiple In_2O_3 nanowires operating at room temperature. The multiwire sensor showed an even lower detection limit of 5 ppb, compared to the 20 ppb limit of single nanowire sensors. This room temperature detection limit is the lowest level so far achieved with all metal oxide film or nanowire sensors. The authors tentatively attribute this improved sensitivity to the formation of nanowire/nanowire junctions between the metal electrodes, a feature available in the multiple nanowire devices (Fig. 6) but missing in the single nanowire devices. Such junctions, when exposed to NO_2 , should form a depleted layer around the intersection and thus block the electron flow

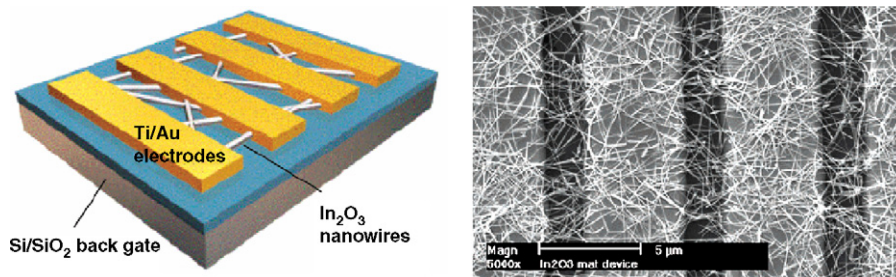


Fig. 6. (Left) Schematic representation of a multiwire device. (Right) Corresponding SEM image of the as-fabricated multiwire devices, where bulk quantities (10^2 to 10^3) of In_2O_3 nanowires are contacted by three electrodes.

in a way more prominent than the surface depletion of the single nanowires with metal contacts. When detecting NO_2 among other common gases such as O_2 , CO , and H_2 using the multiple nanowire devices, selective response to NO_2 was also observed. The authors suggested an “ensemble-averaging effect” as one of possible reasons for the observed high selectivity of the multi-wire sensors. On the basis of their previous study, they suggested that, accordingly, a large ensemble of In_2O_3 nanowires, with an appropriate doping level distribution, could have two opposite sensing responses canceling out each other and resulting in the immunity to NH_3 . This unique property of In_2O_3 nanowires offers a new way to achieve selectivity, as compared to the conventional technique of using permeable polymer coatings [79].

Inspired by the aforementioned results, they have explored using In_2O_3 nanowires to investigate the chemical gating effect of small organic molecules with amine or nitro groups [80]. The amino groups in both butylamine and 3-(aminopropyl) triethoxysilane were found to donate electrons to the n-type In_2O_3 nanowires and resulted in enhanced carrier concentrations and also conductance, whereas the nitro groups in butyl nitrite withdrew electrons from the nanowires, and led to reduced carrier concentrations and conduction. To better study the chemical gating effect of low-density lipoproteins (LDL) using In_2O_3 nanowires, Zhou et al. studied carbon nanotube transistors as a comparison [81]. The adsorption of LDL on these two different surfaces was investigated, which revealed a tenfold more LDL particle adsorption on carbon nanotubes than on In_2O_3 nanowires because of hydrophobic/hydrophilic interactions. The conductance of the field-effect transistors based on the nanowires and nanotubes showed complementary response after the adsorption of LDL: while the In_2O_3 nanowire transistors exhibited higher conductance accompanied by a negative shift of the threshold voltage, the carbon nanotube transistors showed lower conductance after the exposure (shown in Fig. 7). This is attributed to the complementary doping type of In_2O_3 nanowires (n-type) and carbon nanotubes (p-type).

Zhou and co-workers [82] also achieved the In_2O_3 nanowire surface functionalization via a simple and mild self-assembling

process, utilizing 4-(1,4-dihydroxybenzene) butyl phosphonic acid (HQ-PA). HQ-PA is an electrochemically active molecule containing a hydroquinone group that undergoes reversible oxidation/reduction at low potentials. Oxidized HQ-PA (Q-PA) reacts with a range of functional groups, which can be easily incorporated into biomolecules and other materials, such as thiols, azides, cyclopentadienes, and primary amines.

Zhou and co-workers investigated not only the chemical- and bio-sensors based on In_2O_3 nanowires but also the ultraviolet photodetection properties [83]. They found that In_2O_3 nanowire devices exhibited significantly enhanced conduction under UV exposure and high sensitivities were achieved. They believed that two major mechanisms were active in the photoconductive In_2O_3 nanowires. First of all, because of the affinity between the electrons and the oxidizing O_2 molecules, O_2 can adsorb on the nanowire surface and combine with the nearby free electrons to form an O_2^- layer once the nanowire is exposed to air. This reduces the carrier concentration in the n-type In_2O_3 nanowire and thus suppresses its conductivity. Upon exposure to UV light, the O_2^- ions will recombine with the photo-generated holes and discharge O_2 molecules: $\text{h}^+ + \text{O}_2^- \rightarrow \text{O}_2$. This process helps erase the effect of the surrounding O_2 and brings the nanowire to the original electron-rich state. Secondly, further illumination will generate more electron-hole pairs in the conduction and valence bands, and these photogenerated carriers can significantly increase the conductance of the nanowire.

Also, Chu et al. [84] investigated the gas sensing properties of In_2O_3 nanowires films. The results revealed that the sensors exhibited higher response and good selectivity to $\text{C}_2\text{H}_5\text{OH}$ at 370°C . The response time was about 10 s and recovery time was shorter than 20 s.

5.3.2. SnO_2 nanowire sensors

Moskovits and co-workers [85] reported the O_2 and CO sensing properties based on an individual SnO_2 nanowire. Exposure to oxygen recreated the surface acceptor states, thereby reducing the nanowire's conductance, and restored the temperature dependence of the conductance to the exponential form typical of

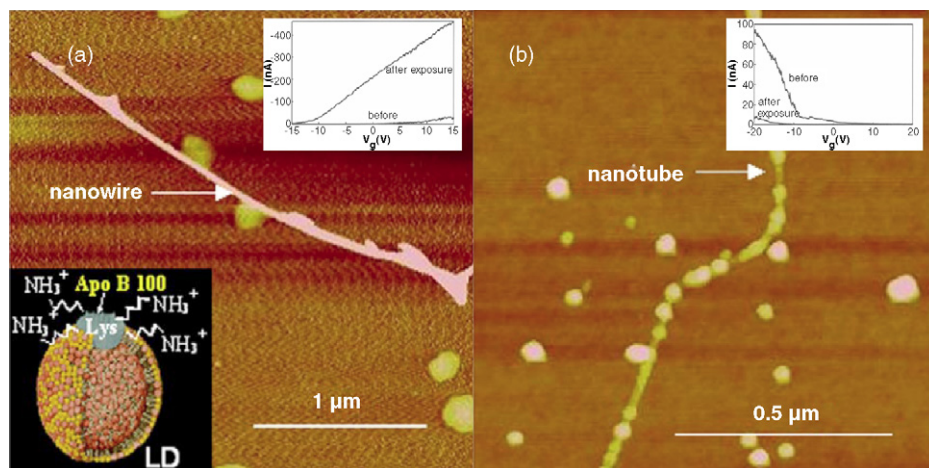


Fig. 7. Typical AFM images of LDL adsorption on an In_2O_3 nanowire (a) and a carbon nanotube (b). The inset, $I - V_g$ curves of (a) an In_2O_3 nanowire device at $V = -0.1$ V and (b) carbon nanotube transistor at $V = 0.1$ V before and after exposure to LDL.

intrinsic semiconductors. Combustible gases like CO react with pre-adsorbed oxygen species to form carbon monoxide reducing the steady-state surface oxygen concentration and donating a few electrons back into the bulk, and resulting in an increased conductivity which depends monotonically on the gas phase partial pressure of CO. The electron exchange between the surface states and the bulk takes place within a surface layer whose thickness is of the order of the Debye length, λ_D .

In particular, they presented experimental observations [86] that the rates of oxygen adsorption–desorption and that of the catalytic oxidation of CO, taking place on the surface of a SnO₂ nanowire, along with the specific reaction channel, were changed by varying the electron density inside the nanowire, with the help of a gate potential. It was found that manipulating the number of electrons inside a nanowire affected the chemical reactivity and selectivity of its surface.

By close analogy with processes taking place in macroscopic metal oxide semiconductor field-effect transistor (MOSFET) gas sensors, Moskovits' group [87] determined the electron-transport properties of individual tin oxide nanowires configured as FETs over a wide temperature range in various atmospheres comprised of mixtures of N₂/O₂/CO. Because of their large surface-to-volume ratios, the bulk electronic properties of the nanowires were found to be controlled almost entirely by the chemical processes taking place at their surface, which could in turn be modified by controlling the gate potential. Thus, the rate and extent of oxygen ionosorption and the resulting rate and extent of catalytic CO oxidation reaction on the nanowire's surface could be controlled and even entirely halted by applying a negative enough gate potential.

Xia and co-workers [88] prepared a polycrystalline SnO₂ nanowires film for gas sensing. The nanowire film sensor exhibited high sensitivity and reversibility when exposed to ethanol vapor ($\sim 6\%$, $V_{\text{ethanol}}/V_{\text{air}}$), 20 ppm CO, and 500 ppm H₂. The authors suggested that this could be attributed to the intrinsically small grain size and high surface-to-volume ratios associated with the polycrystalline nanowires. A thin layer of the film close to the surface could be activated during gas detection due to the dense structure of a compact film. The small grains of SnO₂ in the nanowires allowed the sensors to be operated in the most sensitive, grain-controlled mode.

Similarly, Baratto et al. [89] tested the gas sensing of SnO₂ nanowires. The response of the sensor was highly selective toward humidity and other polluting species, such as CO and NH₃. Wan et al. [90] synthesized Sb-doped SnO₂ nanowires and exploited the application for gas sensors. It was found that the response range to ethanol was wide (10–1000 ppm) at 300 °C. The response and recovery times to 10 ppm ethanol were only about 1 and 5 s, respectively. Mulla and co-workers [91] reported the unique response towards NO₂ and LPG based on Ru-doped SnO₂ nanowires. The nanowires exhibited a highly selective sensing behavior towards NO₂ at room temperature.

Mathur et al. [92] studied the photosensing properties of SnO₂ nanowires and found that the photoconductance of the SnO₂ nanowire showed a strong modulation that was dependent on the average radial dimensions.

5.3.3. ZnO nanowire sensors

Wang and co-workers [93] studied the sensing characteristics to ethanol of a ZnO nanowire sensor fabricated with the MEMS technology. It was found that the sensor had a high sensitivity to 200 ppm ethanol at 300 °C. Continuously they fabricated individual ZnO nanowire transistors and characterized them in a vacuum chamber under different oxygen pressures [94]. The transistors exhibited high sensitivity to oxygen, which led to a change of the source drain current and a shift of the threshold voltage. Lu and co-workers [95] also investigated the electrical transport properties of ZnO nanowire FETs. Also, Wang and co-workers [96] fabricated a Cd-doped ZnO nanosensor device using MEMS techniques for humidity detection. Similarly, Zhu et al. [97] found that ZnO nanowires film exhibited high humidity sensitivity, good long-term stability and fast response time.

A ZnO nanowire field-effect chemical sensor and their sensing properties for NO₂ and NH₃ were presented by Fan and Lu [98]. They observed that the gate potential could affect the detection sensitivity, and the adsorbed gas molecules could be electrically desorbed by applying a large negative gate voltage. Zhang and co-workers [99] studied NH₃-sensing characteristics of ZnO nanowires in terms of a quartz crystal microbalance (QCM) at room temperature. The ZnO nanowires showed high sensitivity to ammonia in the range of 40–1000 ppm. The response time was as fast as ~ 5 s at any concentration (40–1000 ppm). Meanwhile, they found that the response varied with the thickness of the ZnO nanowires layer. Pearton and co-workers [100] found that single ZnO nanowires coated with Pt clusters by sputtering selectively detected 500 ppm hydrogen at room temperature.

Also, Yang and co-workers [101,102] showed the sensing to ultraviolet light of individual ZnO nanowires.

5.3.4. Other oxide nanowire sensors

Yu et al. [103] revealed the effective applications of a two-terminal device fabricated with an individual crystalline β -Ga₂O₃ nanowire. The device showed good sensing response to ethanol gas at an operating temperature of 100 °C. The measured response time of the sensor was about 2.5 s. The ethanol concentration changed from 0 to 6000 ppm. Chen and Chen [104] studied the response to CO and ethanol of Ti-doped Ga₂O₃ nanowire films. Yu et al. [105] demonstrated the electrical responses of well-aligned V₂O₅ nanowires to helium gas and environmental pressures. The authors suggested that the conduction mechanism of the vanadium pentoxide nanowires was related to the modulation of the hopping distance [106], i.e. the hopping distance was shortened by the physical adsorption of the helium gas, whereas it was lengthened by the normal air. V₂O₅ nanofibre-based sensors were proven capable of detecting organic amines with extremely high sensitivity and selectivity at room temperature by Vossmeier and co-workers [107]. The limit of detection for 1-butylamine was found to be less than 30 ppb, which was far below the detection limit of the human olfactory system (ranging from around 240–13.4 ppm [108]). The change of conductance may be attributed to intercalation of the amine into the layered structure of the nanofibres and sorption at the nanofibre/electrode interface.

5.4. Polymer nanowire sensors

Yun et al. [59] fabricated a single conducting polypyrrole wire with a 200 nm thickness, a 500 nm width and a 3 μm length, and demonstrated its pH sensing. The conductivity of the polypyrrole wire was directly proportional to the pH.

Kaner and co-workers [109,110] developed polyaniline nanofiber thin film sensors and compared them to conventional polyaniline sensors. They explored five different response mechanisms such as acid doping (HCl), base dedoping (NH_3), reduction (with N_2H_4), swelling (with CHCl_3), and polymer chain conformational changes (induced by CH_3OH). Their high surface area, porosity and small diameters enhanced diffusion of molecules and dopants into the nanofibers. When the polyaniline was exposed to HCl, a rapid drop in resistance was observed within a short period of time. This doping of polyaniline is achieved by protonation of the imine nitrogens by HCl. The charge created along the backbone by this protonation was counter-balanced by the resulting negatively charged chloride counterions. The change in conductivity was brought about by the formation of polarons (radical cations) that traveled along the polymer backbone. The mechanism for base dedoping of polyaniline is different than that for acid doping and may account for the slower response times and smaller resistance changes. In addition to the emeraldine salt and base forms, polyaniline can exist in several different oxidation states, including the fully reduced leucoemeraldine form, the half-oxidized emeraldine form, and the fully oxidized pernigraniline form. The oxidation states can either be controlled by synthetic conditions or oxidation–reduction reactions; hydrazine is known to convert the emeraldine form to the leucoemeraldine form. The sensing mechanism for chloroform molecules sensing is that chloroform molecules are relatively small and can diffuse efficiently into the polymeric matrix, which expands the structure and decreases the conductivity of the film. Small alcohol molecules have a different response mechanism to polyaniline from those of halogenated solvents. They interact with the nitrogen atoms of polyaniline, leading to an expansion of the compact polymer chains into a linear form, thus decreasing the resistance of the film.

Craighead and co-workers [111] created individual polyaniline/poly(ethylene oxide) nanowire sensors for detecting NH_3 at concentrations as low as 0.5 ppm with rapid response and recovery time. Tseng and co-workers [112] demonstrated real-time electronic sensing in the gas phase and in solution using an array of polyaniline nanoframework–electrode junctions. This sensing device could be used for chemical sensing of HCl, NH_3 and ethanol vapor, and also for pH sensing of aqueous NaCl solutions.

Also of interest is the work of Boussaad and Tao [113] who studied a tuning-fork sensor based on a polymer wire (nitrocellulose/toluene sulfonamide formaldehyde resin). The wire was glued onto the prongs of the tuning fork; the diameter of a small portion of the wire was reduced down to 100–500 nm with a focused ion beam system. Exposing the polymer wire to ethanol vapor changed the resonance frequency and thus the oscillation amplitude. The amplitude recovered after removing the vapor

source and flushing the chamber with N_2 . The change for 30 ppm was quicker and larger than that for 15 ppm. The authors suggested that the adsorption of organic vapors changed both the mass and the spring constant of the polymer wire.

5.5. Other nanowire sensor

Lieber et al. [114] reported optical studies of individual free-standing InP nanowires that demonstrated giant polarization anisotropy in photoluminescence (PL) measurements and the use of these InP nanowires as photoconductivity (PC)-based photodetectors. The PL properties of single InP nanowires recorded at room temperature with the polarization of the exciting laser parallel and perpendicular to the nanowire showed a giant polarization anisotropy. Wang and co-workers [115] fabricated ZnSnO_3 nanowire gas sensors which showed a very high sensitivity and sensitivity to 1 ppm ethanol at 300 °C. Both the response and the recovery time were about 1 s. Osterloh and co-workers [116] studied the conductivity of LiMo_3Se_3 nanowire films in the presence of organic vapors such as methanol, THF, acetonitrile, and DMSO. Zhou and co-workers [117] studied the photoconduction of single-crystal GaN nanowires. The nanowire transistors exhibited a substantial increase in conductance upon UV light exposure. Besides the selectivity to different light wavelengths, extremely short response and recovery time were also obtained, as well as the great reversibility of the nanowire between the high- and low-conductivity states.

6. Conclusion and remarks

This article provides a review on current research status of chemical sensors based on various new types of nanostructured materials such as nanotubes, nanorods, nanobelts, and nanowires. These nanostructure-based sensors represent a powerful detection platform for a broad range including biological sensors, electrochemical sensors, gas sensors, optical sensors, pH sensors, orientation sensors, etc. The sensing devices include individual nanostructured sensors, multi-nanostructured sensors, MOSFET-based sensors, and nanostructured film sensors, and so on. These nanosensor devices have a number of key features, including high sensitivity, exquisite selectivity, fast response and recovery, and potential for integration of addressable arrays on a massive scale, which sets them apart from other sensors technologies available today. In the near future, we argue that these advances could and should be developed at molecule level detection in simple nanosensor devices. However, there are still a lot of issues to be investigated:

- (1) For sensing mechanism of nanosensors, many authors believe that it can be attributed to be high surface-to-volume ratios, porosity, small diameters, and the reactions between the oxygen species O^{2-} , O^- and O_2^- on the surface and samples. However, these aspects had been used for analyzing the sensing reactions long before, so we should explore the sensing mechanism in detail coupled with their special nanostructures. In addition, the chemical sensors based on nanostructured materials may have the required sensitivity,

but the selectivity of some kinds of sensors needs to be improved.

- (2) Another important research topic is applications of nanosensors to security such as poison, drug (heroin), minim explosive, fire damp explosion in coal mine, nanoparticles in air, and so on, which would represent a clear application of nanotechnology and, more importantly, a substantial benefit to humankind.
- (3) Finally, development of fabrication techniques of nanostructures coupled with other nano- and microstructures fabricated using “top down” techniques is needed. Especially for biosensor, for example, we believe that advances in capabilities of assembling larger and more complex nanosensor arrays and integrating them with first conventional and later nanoscale electronics for processing will lead to exquisitely powerful sensor systems that help to enable the potential on disease diagnosis, genetic screening, and drug discovery, as well as serve as powerful new tools for research in many areas of biology.

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